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Zn doped CdO thin films with enhanced linear and third order nonlinear optical properties for optoelectronic applications

Bairy R.^a 🖂 , Jayarama A.^b, Shivakumar G.K.^a, Patil P.S.^c, Bhat K.U.^d Save all to author list

- ^a Department of Physics, NMAM Institute of Technology, Nitte, Karkala Tq, India
- ^b Department of Physics, Alva's Institute of Engineering and Technology, Moodabidri, India
- ^c Department of Physics, K.L.E. Institute of Technology, Hubballi, India
- ^d Department of Metallurgical and Materials Engineering, NITK Surathkal, India

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Thin films of undoped and zinc doped CdO have been deposited on glass substrate using spinion. MOODBIDEN more related documents in purplying technique with various dopant concentrations of 70 cush and 70 cush a pyrolysis technique with various dopant concentrations of Zn such as 1, 5 and 10%. Influence of Zn doping on CdO thin films for the structural, morphological, optical and nonlinear optical properties are reported. XRD analysis reveals that as prepared pure and Zn doped CdO films show polycrystalline nature with face centered cubic structure. Also, Zn doping does not significantly modify the crystallinity and not much increase in the crystallite size of the film. SEM images shows grains which are uniform and grain size with increase in dopant concentration. The transmittance of the prepared CdO films recorded in the UV visible spectra and it shows 50 to 60% in the visible region. The estimated optical band gap increases from 2.60 to 2.70 eV for various dopant concentrations. The nonlinear

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